

## Features

- $BV_{CEO} > 30V$
- $BV_{EBO} > 8V$
- Continuous Current  $I_C$  to 10A
- Peak Pulse Current  $I_{CM}$  to 20A
- Ultra-Low Saturation Voltage  $V_{CE(sat)} < 30mV$  @ 1A
- High Current  $R_{CE(sat)} = 12m\Omega$  Typical
- Small Form Factor Thermally Efficient Package Enables Higher Density Products
- Wettable Flank for Improved Optical Inspection
- Rated to  $+175^\circ C$  – Ideal for High-Temperature Environments
- Complementary PNP Type: [DXTN80030DFG](#)
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. “Green” Device (Note 3)**
- **An automotive-compliant part is available under a separate datasheet ([DXTN80030DFGQ](#))**

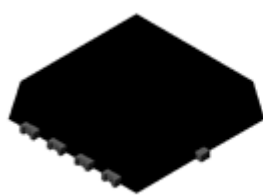
## Mechanical Data

- Package: PowerDI®3333-8
- Package Material: Molded Plastic, “Green” Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.03 grams (Approximate)

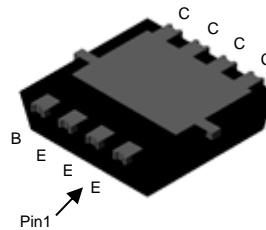
## Applications

- MOSFET & IGBT gate drivers
- Load switches
- Low-voltage regulations
- DC to DC converters
- Motors, solenoids, relays and actuator drivers control

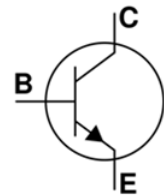
PowerDI3333-8/SWP (Type UX)



Top View



Bottom View



Device Symbol

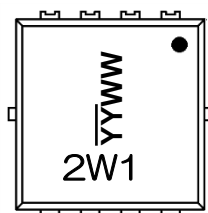
## Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
DXTN80030DFG-7	PowerDI3333-8/SWP (Type UX)	2W1	7	12	2,000	Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information

PowerDI3333-8/SWP (Type UX)



2W1 = Product Type Marking Code  
YYWW = Date Code Marking  
YY = Last Two Digits of Year (ex: 25 = 2025)  
WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated in the United States and other countries.

## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	30	V
Emitter-Base Voltage	V <sub>EBO</sub>	8	V
Continuous Collector Current (Note 5)	I <sub>C</sub>	5	A
Continuous Collector Current (Note 7)	I <sub>C</sub>	10	A
Peak Pulse Current	I <sub>CM</sub>	20	A

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	900	mW
		1.6	W
		2.4	W
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	140	°C/W
		92	°C/W
		62.5	°C/W
Thermal Resistance, Junction to Case (Note 7)	R <sub>θJC</sub>	6.5	°C/W
Thermal Resistance, Junction to Lead (Note 8)	R <sub>θJL</sub>	4.2	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C

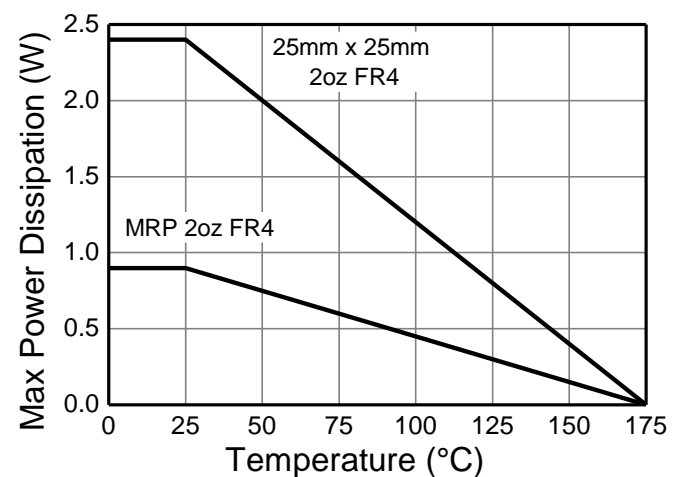
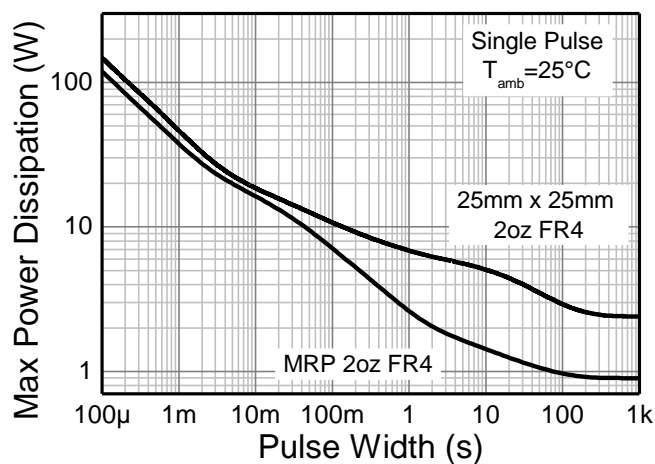
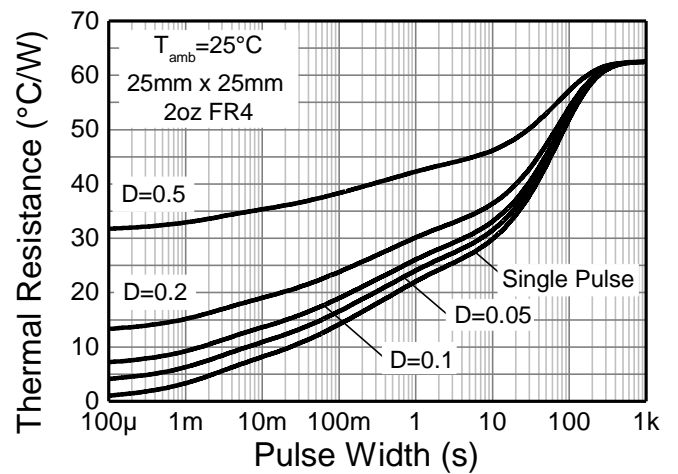
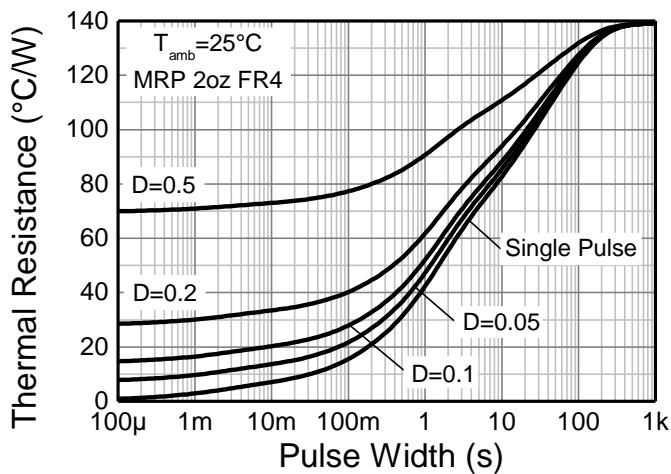
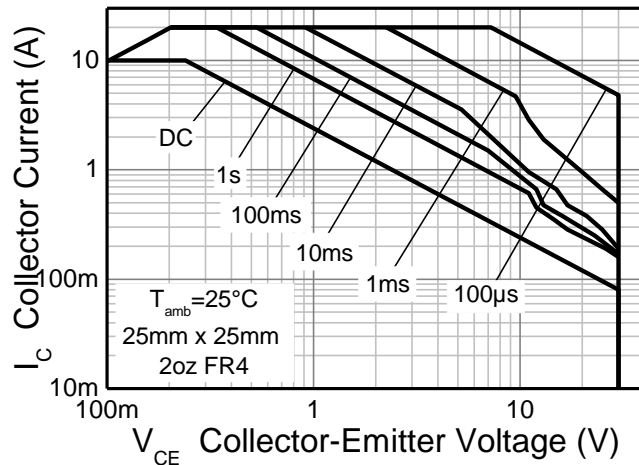
## ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C
Electrostatic Discharge - Charged Device Model	ESD CDM	1,000	V	IV

Notes:

5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady state.
6. Same as Note 5, except the device is mounted on 15mm x 15mm 2oz copper.
7. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
8. Thermal resistance from junction to solder-point (at the collector tab).
9. Refer to JEDEC specifications JESD22-A114, JESD22-A115 and JESD22-C101.

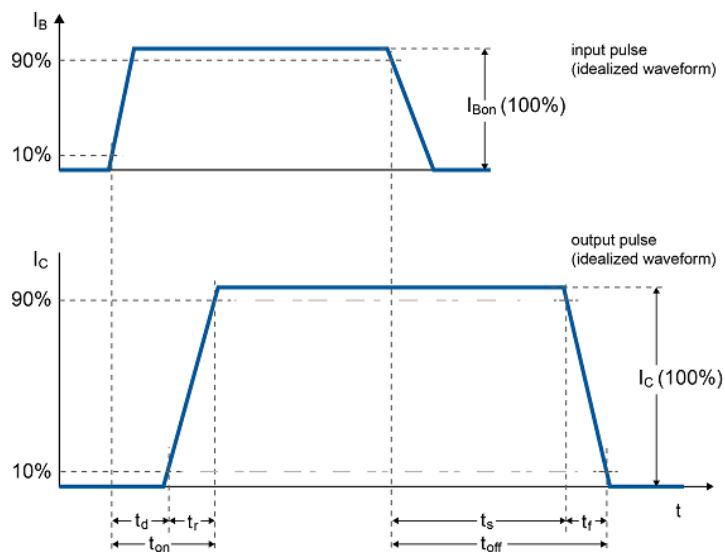
## Thermal Characteristics and Derating Information



**Electrical Characteristics** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

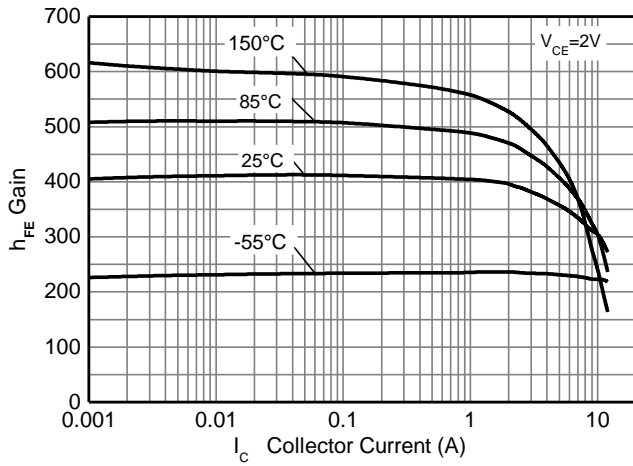
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	80	—	—	V	$I_C = 100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 10)	$BV_{CEO}$	30	—	—	V	$I_C = 10\text{mA}$
Emitter-Collector Breakdown Voltage	$BV_{ECO}$	5	—	—	V	$I_E = 100\mu\text{A}$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	8	—	—	V	$I_E = 100\mu\text{A}$
Collector Cutoff Current	$I_{CBO}$	—	—	100	nA	$V_{CB} = 80\text{V}$
		—	—	10	$\mu\text{A}$	$V_{CB} = 80\text{V}$ , $T_A = +125^\circ\text{C}$
Collector Cutoff Current	$I_{CES}$	—	—	300	nA	$V_{CE} = 24\text{V}$
Emitter Cutoff Current	$I_{EBO}$	—	—	50	nA	$V_{EB} = 7\text{V}$
Collector-Emitter Saturation Voltage (Note 10)	$V_{CE(sat)}$	—	28	—	mV	$I_C = 100\text{mA}$ , $I_B = 1\text{mA}$
		—	17	30	mV	$I_C = 1\text{A}$ , $I_B = 100\text{mA}$
		—	40	65	mV	$I_C = 2\text{A}$ , $I_B = 40\text{mA}$
		—	75	125	mV	$I_C = 5\text{A}$ , $I_B = 100\text{mA}$
		—	120	160	mV	$I_C = 10\text{A}$ , $I_B = 500\text{mA}$
Base-Emitter Saturation Voltage (Note 10)	$V_{BE(sat)}$	—	850	1,000	mV	$I_C = 5\text{A}$ , $I_B = 100\text{mA}$
		—	970	1,150	mV	$I_C = 10\text{A}$ , $I_B = 500\text{mA}$
Base-Emitter Turn-On Voltage (Note 10)	$V_{BE(on)}$	—	750	900	mV	$I_C = 5\text{A}$ , $V_{CE} = 2\text{V}$
		—	760	900	mV	$I_C = 10\text{A}$ , $V_{CE} = 2\text{V}$
DC Current Gain (Note 10)	$h_{FE}$	—	380	—	—	$I_C = 10\text{mA}$ , $V_{CE} = 2\text{V}$
		300	380	550	—	$I_C = 100\text{mA}$ , $V_{CE} = 2\text{V}$
		270	365	—	—	$I_C = 1\text{A}$ , $V_{CE} = 2\text{V}$
		250	350	—	—	$I_C = 2\text{A}$ , $V_{CE} = 2\text{V}$
		200	310	—	—	$I_C = 5\text{A}$ , $V_{CE} = 2\text{V}$
		100	250	—	—	$I_C = 10\text{A}$ , $V_{CE} = 2\text{V}$
Input Capacitance	$C_{ibo}$	—	620	—	pF	$V_{EB} = 0.5\text{V}$ , $f = 1\text{MHz}$
Output Capacitance	$C_{obo}$	—	50	—	pF	$V_{CB} = 10\text{V}$ , $f = 1\text{MHz}$
Current Gain-Bandwidth Product	$f_T$	100	130	—	MHz	$V_{CE} = 10\text{V}$ , $I_C = 100\text{mA}$ $f = 50\text{MHz}$
Turn-On Time	$t_d$	—	13.5	—	ns	$V_{CC} = 10\text{V}$ , $I_C = 5\text{A}$ $I_{B1} = -I_{B2} = 500\text{mA}$
	$t_r$	—	55	—	ns	
Turn-Off Time	$t_s$	—	230	—	ns	
	$t_f$	—	4	—	ns	

Note: 10. Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ . Duty cycle  $\leq 2\%$ .

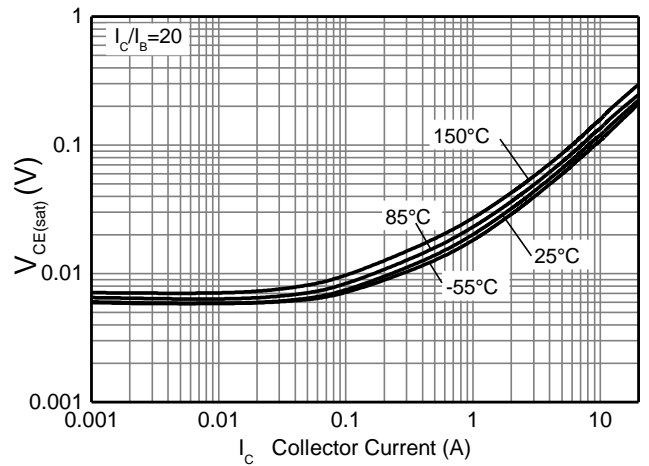


**Fig 6. Timing Waveform**

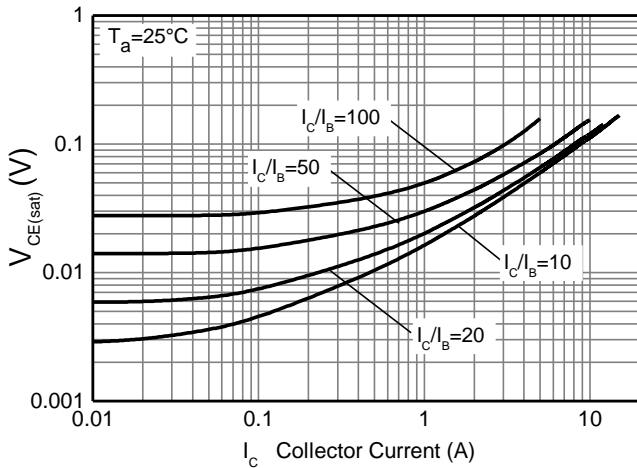
**Typical Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)



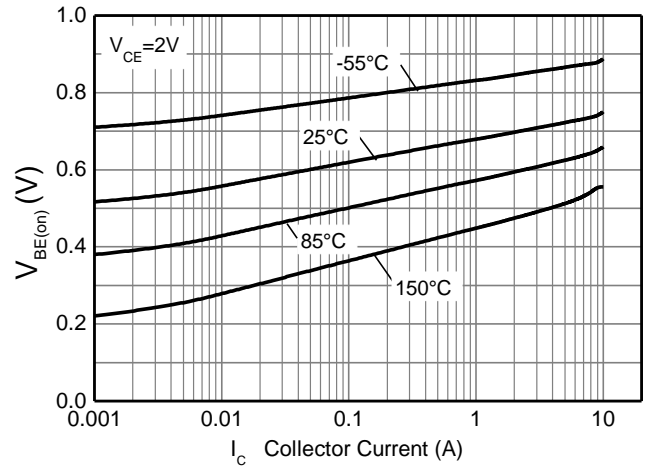
**Fig. 7**  $h_{FE} \text{ v } I_C$



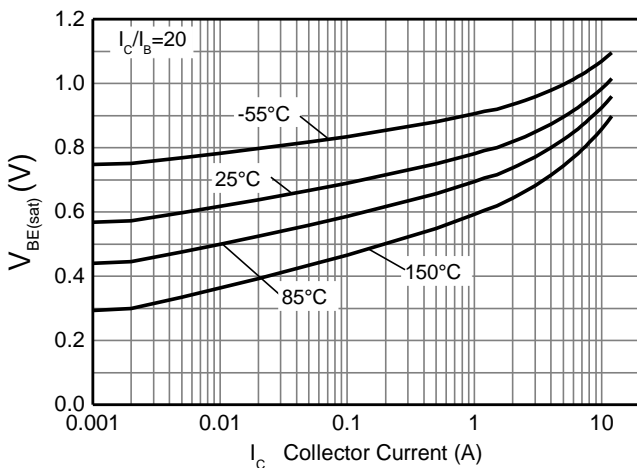
**Fig. 8**  $V_{CE(sat)} \text{ v } I_C$



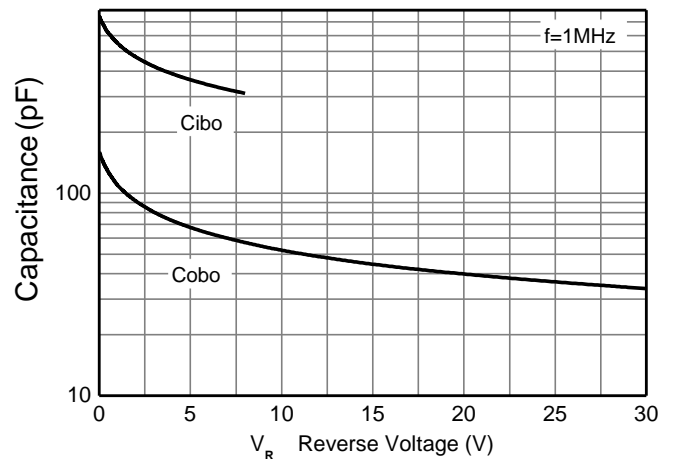
**Fig. 9**  $V_{CE(sat)} \text{ v } I_C$



**Fig. 10**  $V_{BE(on)} \text{ v } I_C$

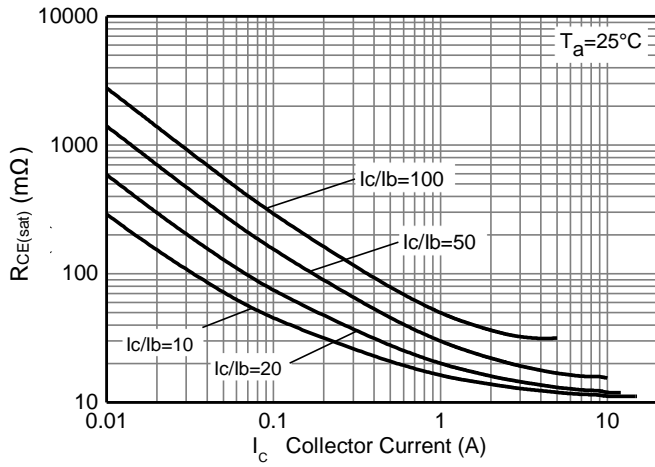


**Fig. 11**  $V_{BE(sat)} \text{ v } I_C$

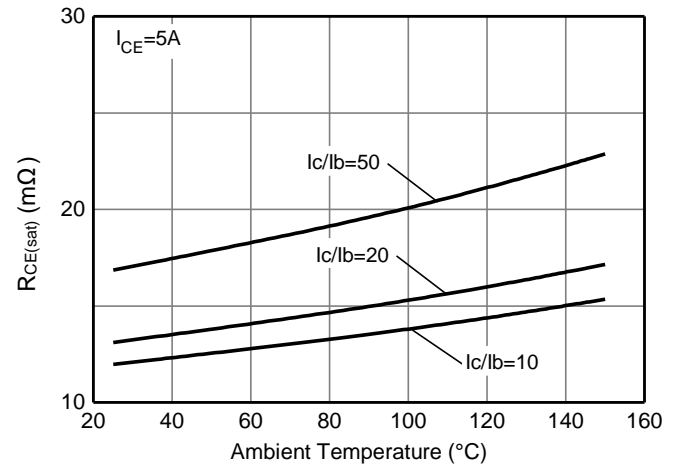


**Fig. 12** Typical Junction Capacitance

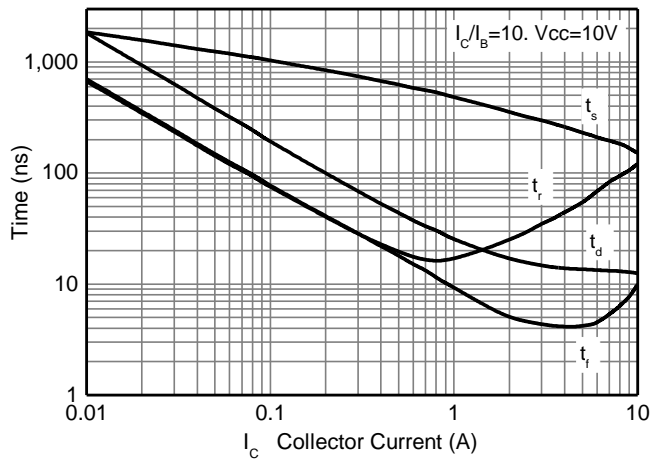
**Typical Electrical Characteristics** (continued) (@T<sub>A</sub> = +25°C, unless otherwise specified.)



**Fig. 13**  $R_{CE(sat)} \text{ v } I_C$



**Fig. 14**  $R_{CE(sat)} \text{ v } T_{amb}$

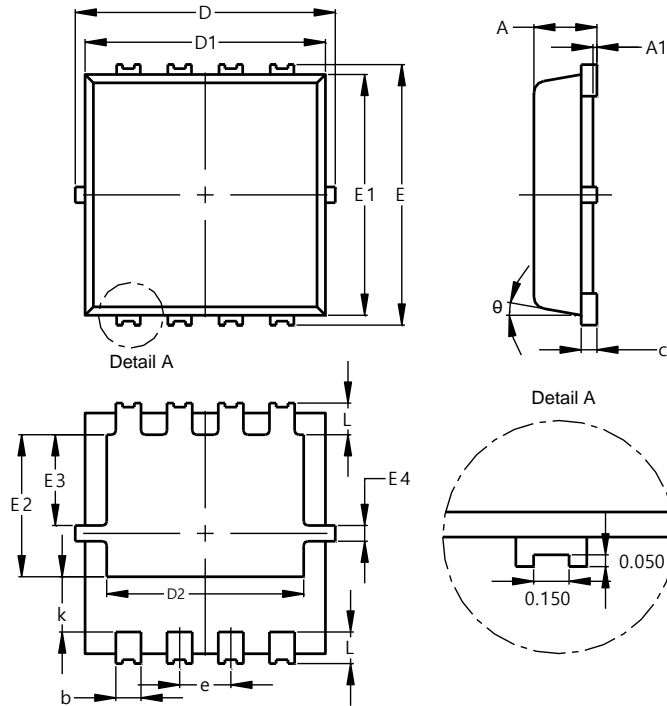


**Fig. 15** Switching Performance

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### PowerDI3333-8/SWP (Type UX)

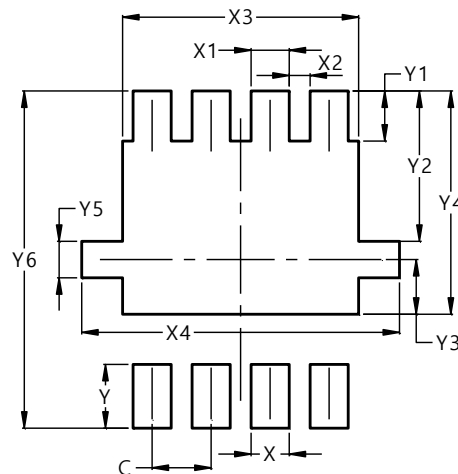


PowerDI3333-8/SWP (Type UX)			
Dim	Min	Max	Typ
A	0.75	0.85	0.80
A1	0.00	0.05	--
b	0.25	0.40	0.32
c	0.10	0.25	0.15
D	3.20	3.40	3.30
D1	2.95	3.15	3.05
D2	2.30	2.70	2.50
E	3.20	3.40	3.30
E1	2.95	3.15	3.05
E2	1.60	2.00	1.80
E3	0.95	1.35	1.15
E4	0.10	0.30	0.20
e	--	--	0.65
k	0.50	0.90	0.70
L	0.30	0.50	0.40
θ	0°	12°	10°
All Dimensions in mm			

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### PowerDI3333-8/SWP (Type UX)



Dimensions	Value (in mm)
C	0.650
X	0.420
X1	0.420
X2	0.230
X3	2.600
X4	3.500
Y	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700

Note: 11. Side wall tin plated package for wettable flanks in AOI.

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